INTEGRATED CIRCUITS



Product specification Supersedes data of 1996 Aug 23 IC24 Data Handbook 1998 May 20





74LVC161

FEATURES

- Wide supply voltage range of 1.2 V to 3.6 V
- In accordance with JEDEC standard no. 8–1A
- Inputs accept voltages up to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels
- Asynchronous reset
- Synchronous counting and loading
- Two count enable inputs for n-bit cascading
- Positive edge-triggered clock
- Output drive capability 50 Ω transmission lines @85°C

DESCRIPTION

The 74LVC161 is a high-performance, low-power, low-voltage, Si-gate CMOS device and superior to most advanced CMOS compatible TTL families.

The 74LVC161 is a synchronous presettable binary counter which features an internal look-head carry and can be used for high-speed counting. Synchronous operation is provided by having all flip-flops clocked simultaneously on the positive-going edge of the clock (CP). The outputs $(Q_0 \text{ to } Q_3)$ of the counters may be preset to a HIGH or LOW level. A LOW level at the parallel enable input (PE) disables the counting action and causes the data at the data inputs (D₀ to D₃) to be loaded into the counter on the positive-going edge of the clock (provided that the set-up and hold time requirements for PE are met). Preset takes place regardless of the levels at count enable inputs (CEP and CET). A low level at the master reset input (MR) sets all four outputs of the flip-flops $(Q_0 \text{ to } Q_3)$ to LOW level regardless of the levels at CP, \overline{PE} , CET and CEP inputs (thus providing an asynchronous clear function).

The look-ahead carry simplifies serial cascading of the counters. Both count enable inputs (CEP and CET) must be HIGH to count. The CET input is fed forward to enable the terminal count output (TC). The TC output thus enabled will produce a HIGH output pulse of a duration approximately equal to a HIGH level output of Q₀. This pulse can be used to enable the next cascaded stage. The maximum clock frequency for the cascaded counters is determined by the CP to TC propagation delay and CEP to CP set-up time, according to the following formula:

f_{max} =

tp_(max) (CP to TC) + t_{SU} (CEP to CP)

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $T_{R} = T_{F} \le 2.5$ ns

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay CP to Q _n CP to TC MR to Q _n MR to TC CET to TC	C _L = 50 pF V _{CC} = 3.3V	4.9 5.7 5.2 5.7 4.5	ns
f _{MAX}	maximum clock frequency		200	MHz
Cl	input capacitance		5.0	pF
C _{PD}	power dissipation capacitance per gate	notes 1 and 2	39	pF

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μ W) $\begin{array}{l} \mathsf{P}_{\mathsf{D}} = \mathsf{C}_{\mathsf{PD}} \times \mathsf{V}_{\mathsf{CC}}^2 \times \mathsf{f}_i + \Sigma \left(\mathsf{C}_{\mathsf{L}} \times \mathsf{V}_{\mathsf{CC}}^2 \times \mathsf{f}_o\right) \text{ where:} \\ \mathsf{f}_i = \mathsf{input} \text{ frequency in MHz; } \mathsf{C}_{\mathsf{L}} = \mathsf{output} \text{ load capacity in pF;} \\ \mathsf{f}_o = \mathsf{output} \text{ frequency in MHz; } \mathsf{V}_{\mathsf{CC}} = \mathsf{supply voltage in V;} \end{array}$

 $\Sigma (C_L \times V_{CC}^2 \times f_0) = \text{sum of the outputs}$ 2. The condition is V₁ = GND to V_{CC}

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
16-Pin Plastic SO	–40°C to +85°C	74LVC161 D	74LVC161 D	SOT109-1
16-Pin Plastic SSOP Type II	–40°C to +85°C	74LVC161 DB	74LVC161 DB	SOT338-1
16-Pin Plastic TSSOP Type I	-40°C to +85°C	74LVC161 PW	74LVC161PW DH	SOT403-1

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PIN CONFIGURATION



LOGIC SYMBOL



PIN DESCRIPTION

PIN NUMBER	SYMBOL	FUNCTION
1	MR	asynchronous master reset (active LOW)
2	СР	clock input (LOW-to-HIGH, edge-triggered)
3,4,5,6	D ₀ to D ₃	data inputs
7	CEP	count enable inputs
8	GND	ground (0V)
9	PE	parallel enable input (active LOW)
10	CET	count enable carry input
14,13,12,11	Q ₀ to Q ₃	flip-flop outputs
15	TC	terminal count output
16	V _{CC}	positive supply voltage

LOGIC SYMBOL (IEEE/IEC)



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FUNCTIONAL DIAGRAM



STATE DIAGRAM



FUNCTION TABLE

OPERATING	INPUTS						OUTPUTS	
MODES	MR	СР	CEP	CET	PE	Dn	Qn	тс
Reset (clear)	L	Х	Х	Х	Х	Х	L	L
Parallel load	H H	↑ ↑	X X	X X		l h	L H	L *
Count	Н	Ŷ	h	h	h	Х	count	*
Hold (do nothing)	H H	X X	I X	X I	h h	X X	q _n q _n	* L

NOTES:

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The TC output is High when CET is High and the counter = is at Terminal Count (HHHH)

=

High voltage level High voltage level one setup time prior to the Low-to-High h = clock transition

Low voltage level =

Low voltage level one setup time prior to the Low-to-High = clock transition

Lower case letters indicate the state of the referenced q = output one setup time prior to the Low-to-High clock transition

Х Don't care = ↑

Low-to-High clock transition =

TYPICAL TIMING SEQUENCE



Typical timing sequence: reset outputs to zero; preset to binary twelve; count to thirteen, fourteen, fifteen, zero, one, and two; inhibit

LOGIC DIAGRAM



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RECOMMENDED OPERATING CONDITIONS

SYMBOL	DADAMETED	CONDITIONS	LIM	LINIT		
STMBOL		CONDITIONS	MIN	MAX		
DC supply voltage (for max. speed performance)			2.7	3.6	V	
V CC	DC supply voltage (for low-voltage applications)		1.2	3.6	v	
VI	DC input voltage range		0	5.5	V	
Vo	DC output voltage range		0	V _{CC}	V	
T _{amb}	Operating free-air temperature range		-40	+85	°C	
t _r , t _f	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7 \text{V}$ $V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V	

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134)

Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +6.5	V
I _{IK}	DC input diode current	V ₁ < 0	-50	mA
VI	DC input voltage	Note 2	-0.5 to +5.5	V
I _{OK}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	±50	mA
Vo	DC output voltage	Note 2	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V_{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		-65 to +150	°C
Ртот	Power dissipation per package – plastic mini-pack (SO) – plastic shrink mini-pack (SSOP and TSSOP)	above +70°C derate linearly with 8 mW/K above +60°C derate linearly with 5.5 mW/K	500 500	mW

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

Product specification

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions voltages are referenced to GND (ground = 0V)

			L	IMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -40°C to +85°C			UNIT	
			MIN	TYP ¹	MAX	1	
Max		$V_{CC} = 1.2V$	V _{CC}				
VIH	HIGH level input voltage	V _{CC} = 2.7 to 3.6V	2.0			V	
V		$V_{CC} = 1.2V$			GND	V	
VIL	LOW level input voltage	V _{CC} = 2.7 to 3.6V			0.8	V	
	HIGH level output voltage	V_{CC} = 2.7V; V_I = V_{IH} or V_{IL} ; I_O = -12mA	$V_{CC} - 0.5$			v	
		V_{CC} = 3.0V; V_I = V_{IH} or V_{IL} ; I_O = -100 μ A	V _{CC} -0.2	V _{CC}			
∨он		V_{CC} = 3.0V; V_I = V_{IH} or V_{IL} ; I_O = -12mA	V _{CC} -0.6				
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL;} I_O = -24 \text{mA}$	V _{CC} -1.0				
		V_{CC} = 2.7V; V_{I} = V_{IH} or V_{IL} ; I_{O} = 12mA			0.40		
V _{OL}	LOW level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$		GND	0.20	V	
		V_{CC} = 3.0V; V_I = V_{IH} or V_{IL} ; I_O = 24mA			0.55		
tı	Input leakage current	V_{CC} = 3.6V; V_{I} = 5.5V or GND		±0.1	±5	μA	
Icc	Quiescent supply current	$V_{CC} = 3.6V; V_I = V_{CC} \text{ or GND}; I_O = 0$		0.1	10	μA	
ΔI _{CC}	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$; $I_O = 0$		5	500	μA	

NOTES:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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AC CHARACTERISTICS

GND = 0 V; t_{f} = t_{f} $\leq\,$ 2.5 ns; C_{L} = 50 pF; R_{L} = 500\Omega; T_{amb} = –40°C to +85°C

		LIMITS							
SYMBOL	PARAMETER	WAVEFORM	V _{CC}	= 3.3V ±0).3V	V _{CC} =	= 2.7V	V _{CC} = 1.2V	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	TYP	1
t _{PHL} t _{PLH}	Propagation delay CP to Qn	1	-	4.9	8.0	-	9.0	24	ns
t _{PHL} t _{PLH}	Propagation delay CP to TC	1	-	5.7	9.5	-	11	28	ns
t _{PHL} t _{PLH}	Propagation delay CET to TC	2	-	4.5	7.8	-	8.8	22	ns
t _{PHL}	Propagation delay MR to Qn	3	-	5.2	9.0	-	10	28	ns
t _{PHL}	Propagation delay MR to TC	3	-	5.7	10	-	11	20	ns
t _W	Clock pulse width HIGH or LOW	1	4.0	1.2	-	5.0	-	-	ns
t _W	Master reset width LOW	3	3.0	1.6	-	4.0	-	-	ns
t _{rem}	Removal time MR to CP	3	0	-0.3	-	0	-	-	ns
t _{su}	Set-up time D _n to CP	4	2.5	1.0	-	3.0	-	-	ns
t _{su}	Set-up time PE to CP	4	3.0	1.2	-	3.5	-	-	ns
t _{su}	Set-up time CEP, CET to CP	5	5.0	2.1	-	5.5	-	-	ns
t _h	Hold time D _n , PE, CEP, CET to CP	4, 5	0	-1.7	-	0	-	-	ns
f _{max}	Maximum clock pulse frequency	1	125	200	-	110	-	-	MHz

NOTE:

1. These typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

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AC WAVEFORMS

 V_M = 1.5 V at $V_{CC} \geq 2.7$ V V_M = 0.5 • V_{CC} at V_{CC} < 2.7 V V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.



Waveform 1. Clock (CP) to outputs (Q_n, TC) propagation delays, the clock pulse width and the maximum clock frequency.



Waveform 2. Input (CET) to output (TC) propagation delays.



Waveform 3. Master reset (\overline{MR}) pulse width, the master reset to output (Q_n , TC) propagation delays and the master reset to clock (CP) removal times.



Waveform 4. Setup and hold times for the input (D_n) and parallel enable input (PE).



Waveform 5. CEP and CET setup and hold times.

TEST CIRCUIT





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1998 May 20



OUTLINE REFERENCES				EUROPEAN		
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT338-1		MO-150AC				-94-01-14- 95-02-04

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94-07-12

95-04-04

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SOT403-1

MO-153

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DEFINITIONS					
Data Sheet Identification	Product Status	Definition			
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.			
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.			
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